

1MBI1600U4C-170

IGBT MODULE (U series) 1700V / 1600A / 1 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines

Maximum Ratings and Characteristics

Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

| Items | Symbols | Conditions | | Maximum ratings | Units | |
|---------------------------------------------------------|----------------------|------------|---------|-----------------|-------|--|
| Collector-Emitter voltage | Vces | | | 1700 | V | |
| Gate-Emitter voltage | Vges | | | ±20 | V | |
| Collector current | lc | Continuous | Tc=25°C | 2400 | | |
| | | | Tc=80°C | 1600 | | |
| | Ic pulse | 1ms | Tc=25°C | 4800 | ۸ | |
| | | | Tc=80°C | 3200 | A | |
| | -lc | | | 1600 | | |
| | -lc pulse | 1ms | | 3200 | | |
| Collector power dissipation | Pc | 1 device | | 9760 | W | |
| Junction temperature | Тј | | | 150 | °C | |
| Storage temperature | Tstg | | | -40 to +125 | °C | |
| Isolation voltage Between terminal and copper base (*1) | Viso | AC : 1min. | | 3400 | VAC | |
| Screw torque | Mounting (*2) | | | 5.75 | | |
| | Main Terminals (*2) | | | 10 | N∙m | |
| | Sense Terminals (*2) | | | 2.5 | | |

Note *1: All terminals should be connected together when isolation test will be done.

Note *2: Recommendable value : Mounting : 4.25-5.75 N·m (M6), Main Terminal : 8-10 N·m (M8), Sense Terminal : 1.7-2.5 N·m (M4)

• Electrical characteristics (at Tj= 25°C unless otherwise specified)

| Itomo | Symbolo | Conditions | | | Characteristics | | |
|-----------------------------------------------------|-----------------------|-----------------------------------------------------------------------------------------|----------|------|-----------------|------|-------|
| Items | Symbols | Symbols Conditions | | min. | typ. | max. | Units |
| Zero gate voltage collector current | Ices | V _{GE} = 0V, V _{CE} = 1700V | | - | - | 1.0 | mA |
| Gate-Emitter leakage current | Iges | $V_{CE} = 0V, V_{GE} = \pm 20V$ | | - | - | 3200 | nA |
| Gate-Emitter threshold voltage | V _{GE (th)} | V _{CE} = 20V, I _c = 1600mA | | 5.5 | 6.5 | 7.5 | V |
| Collector-Emitter saturation voltage | V _{CE (sat)} | O_V _{GE} = 15V I _c = 1600A | Tj=25°C | - | 2.47 | 2.65 | - V |
| | (main terminal) | | Tj=125°C | - | 2.87 | - | |
| | V _{CE (sat)} | | Tj=25°C | - | 2.25 | 2.40 | |
| | (chip) | | Tj=125°C | - | 2.65 | - | |
| Input capacitance | Cies | V _{GE} = 0V, V _{CE} = 10V, f = 1 | MHz | - | 150 | - | nF |
| Turn-off time ton tr toff tf | ton | | | - | 1.80 | - | μs |
| | tr | $V_{cc} = 900V, I_c = 1600A$ | - | 0.85 | - | | |
| | toff | -V _{GE} = ±15V, Tj = 125°C -R _{gon} = 2.7Ω, R _{goff} = 1Ω | | - | 1.30 | - | |
| | tf | 1 (gon - 2.7 32, 1 (gon - 1 32 | - | 0.35 | - | | |
| Forward on voltage V⊧ (main t V⊧ (chip) | VF | | Tj=25°C | - | 2.02 | 2.40 | |
| | (main terminal) | V _{GE} = 0V | Tj=125°C | - | 2.22 | - | V |
| | VF | I⊧ = 1600A | Tj=25°C | - | 1.80 | 2.15 | |
| | (chip) | | Tj=125°C | - | 2.00 | - | |
| Reverse recovery time | trr | I _F = 1600A | • | - | 0.35 | - | μs |
| Lead resistance, terminal-chip (*3) | R lead | | | - | 0.134 | - | mΩ |

Note *3: Biggest internal terminal resistance among arm.

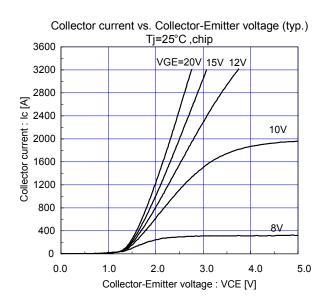
Thermal resistance characteristics

| Symbolo | Conditions | Characteristics | | | Units |
|-----------------------------------------------|----------------------------|----------------------|------------------------------------|------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Symbols | Conditions | min. | typ. | max. | Units |
| Thermal resistance (1device) Rth(j-c) | IGBT | - | - | 0.013 | |
| | FWD | - | - | 0.023 | °C/W |
| Rth(c-f) | with Thermal Compound (*4) | - | 0.006 | - | |
| | | Rth(j-c) IGBT FWD | SymbolsConditionsRth(j-c)IGBT-FWD- | SymbolsConditionsmin.typ.Rth(j-c)IGBTFWD | Symbols Conditions min. typ. max. Rth(j-c) IGBT - - 0.013 FWD - - 0.023 |

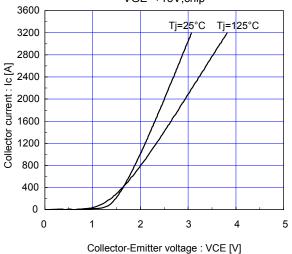
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

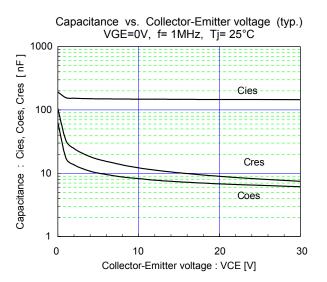


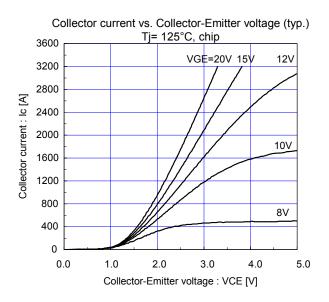
Characteristics (Representative)



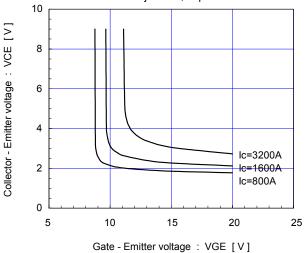
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) VGE=+15V,chip

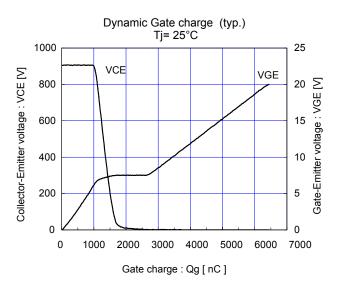


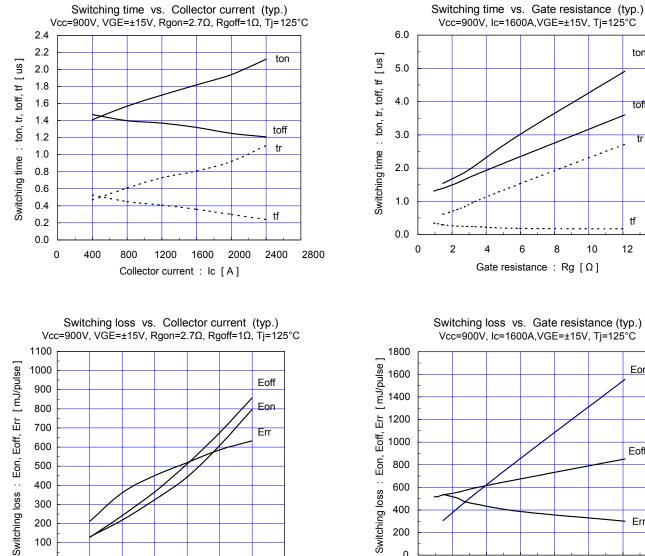




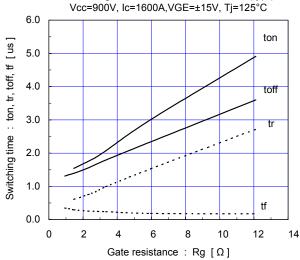
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj=25°C ,chip



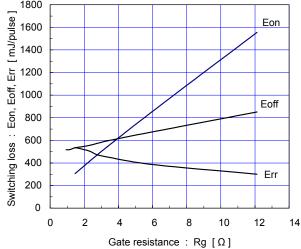


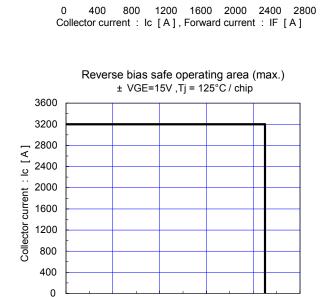


Err

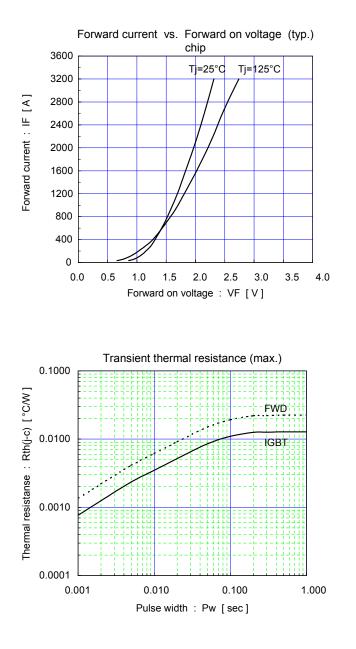


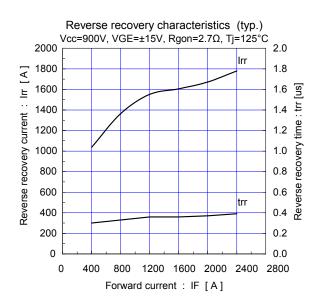
Switching loss vs. Gate resistance (typ.) Vcc=900V, Ic=1600A, VGE=±15V, Tj=125°C



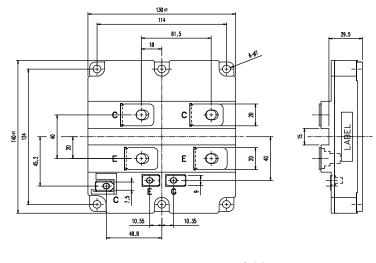


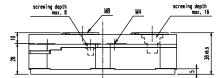
Collector - Emitter voltage : VCE [V]



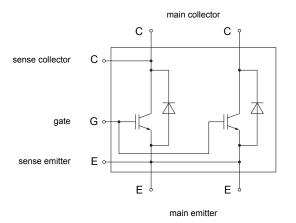


Outline Drawings, mm





Equivalent Circuit Schematic



WARNING

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